

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

SU-HWAN OH, ET AL.

Application No.:

Filed:

For: **Widely Tunable Sampled-Grating
Distributed Feedback Laser Diode**

Art Group:

Examiner:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Date: 12/3/07

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP


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*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number. ²Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08B (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wir) 08/11/2003.
Send To: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Information Disclosure Statement

New U.S. Patent Application for
**WIDELY TUNABLE SAMPLED-GRATING
DISTRIBUTED FEEDBACK LASER DIODE**

Our Ref. No.: P03E5009/US/jk

Reference No.:

- (1) US Patent No. 5,784,183
- (2) JP Laid-Open No. 7-273400

(3) Asymmetric Sampled Grating Laser Array for a
Multiwavelength WDM Source

*(IEEE PHOTONICS TECHNOLOGY LETTERS, VOL. 14, NO. 12, DECEMBER 2002, PAGES
1656-1658)*